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Kind regards,

Team Nexperia

# PDTA113E series

PNP resistor-equipped transistors; R1 = 1 k $\Omega$ , R2 = 1 k $\Omega$

Rev. 05 — 2 September 2009

Product data sheet

## 1. Product profile

### 1.1 General description

PNP Resistor-Equipped Transistors (RET).

Table 1. Product overview

Type number	Package			NPN complement
	NXP	JEITA	JEDEC	
PDTA113EE	SOT416	SC-75	-	PDTC113EE
PDTA113EK	SOT346	SC-59A	TO-236	PDTC113EK
PDTA113EM	SOT883	SC-101	-	PDTC113EM
PDTA113ES <sup>[1]</sup>	SOT54 (TO-92)	SC-43A	TO-92	PDTC113ES
PDTA113ET	SOT23	-	TO-236AB	PDTC113ET
PDTA113EU	SOT323	SC-70	-	PDTC113EU

[1] Also available in SOT54A and SOT54 variant packages (see [Section 2](#))

### 1.2 Features

- Built-in bias resistors
- Reduces component count
- Simplifies circuit design
- Reduces pick and place costs

### 1.3 Applications

- General purpose switching and amplification
- Circuit drivers
- Inverter and interface circuits

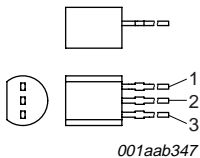
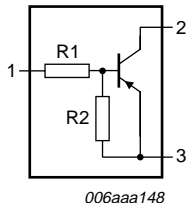
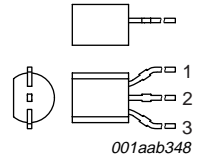
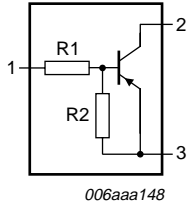
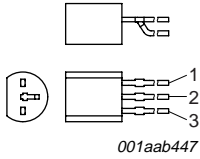
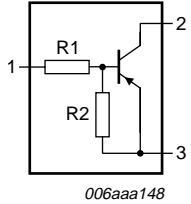
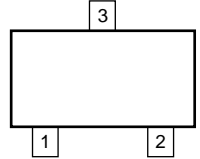
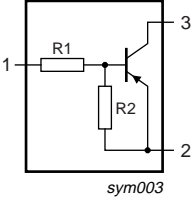
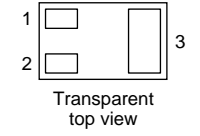
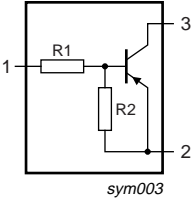
### 1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V <sub>CEO</sub>	collector-emitter voltage	open base	-	-	-50	V
I <sub>O</sub>	output current (DC)		-	-	-100	mA
R1	bias resistor 1 (input)		0.7	1	1.3	k $\Omega$
R2/R1	bias resistor ratio		0.8	1	1.2	

**2. Pinning information**

**Table 3. Pinning**

Pin	Description	Simplified outline	Symbol
<b>SOT54</b>			
1	input (base)	 <p>001aab347</p>	 <p>006aaa148</p>
2	output (collector)		
3	GND (emitter)		
<b>SOT54A</b>			
1	input (base)	 <p>001aab348</p>	 <p>006aaa148</p>
2	output (collector)		
3	GND (emitter)		
<b>SOT54 variant</b>			
1	input (base)	 <p>001aab447</p>	 <p>006aaa148</p>
2	output (collector)		
3	GND (emitter)		
<b>SOT23, SOT323, SOT346, SOT416</b>			
1	input (base)	 <p>006aaa144</p>	 <p>sym003</p>
2	GND (emitter)		
3	output (collector)		
<b>SOT883</b>			
1	input (base)	 <p>Transparent top view</p>	 <p>sym003</p>
2	GND (emitter)		
3	output (collector)		

### 3. Ordering information

Table 4. Ordering information

Type number	Package		Version
	Name	Description	
PDTA113EE	SC-75	plastic surface mounted package; 3 leads	SOT416
PDTA113EK	SC-59A	plastic surface mounted package; 3 leads	SOT346
PDTA113EM	SC-101	leadless ultra small plastic package; 3 solder lands; body 1.0 × 0.6 × 0.5 mm	SOT883
PDTA113ES <sup>[1]</sup>	SC-43A	plastic single-ended leaded (through hole) package; 3 leads	SOT54
PDTA113ET	-	plastic surface mounted package; 3 leads	SOT23
PDTA113EU	SC-70	plastic surface mounted package; 3 leads	SOT323

[1] Also available in SOT54A and SOT54 variant packages (see [Section 2](#) and [Section 9](#)).

### 4. Marking

Table 5. Marking codes

Type number	Marking code <sup>[1]</sup>
PDTA113EE	16
PDTA113EK	17
PDTA113EM	G4
PDTA113ES	TA113E
PDTA113ET	*15
PDTA113EU	*14

[1] \* = -: made in Hong Kong  
 \* = p: made in Hong Kong  
 \* = t: made in Malaysia  
 \* = W: made in China

## 5. Limiting values

**Table 6. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit	
V <sub>CBO</sub>	collector-base voltage	open emitter	-	-50	V	
V <sub>CEO</sub>	collector-emitter voltage	open base	-	-50	V	
V <sub>EBO</sub>	emitter-base voltage	open collector	-	-10	V	
V <sub>I</sub>	input voltage					
	positive		-	+10	V	
	negative		-	-10	V	
I <sub>O</sub>	output current (DC)		-	-100	mA	
I <sub>CM</sub>	peak collector current		-	-100	mA	
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C				
	SOT416		[1]	-	150	mW
	SOT346		[1]	-	250	mW
	SOT883		[2][3]	-	250	mW
	SOT54		[1]	-	500	mW
	SOT23		[1]	-	250	mW
	SOT323		[1]	-	200	mW
	T <sub>stg</sub>	storage temperature		-65	+150	°C
T <sub>j</sub>	junction temperature		-	150	°C	
T <sub>amb</sub>	ambient temperature		-65	+150	°C	

[1] Refer to standard mounting conditions

[2] Reflow soldering is the only recommended soldering method.

[3] Refer to SOT883 standard mounting conditions; FR4 printed-circuit board with 60  $\mu$ m copper strip line.

## 6. Thermal characteristics

**Table 7. Thermal characteristics**

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air					
	SOT416		[1]	-	-	833	K/W
	SOT346		[1]	-	-	500	K/W
	SOT883		[2][3]	-	-	500	K/W
	SOT54		[1]	-	-	250	K/W
	SOT23		[1]	-	-	500	K/W
	SOT323		[1]	-	-	625	K/W

[1] Refer to standard mounting conditions.

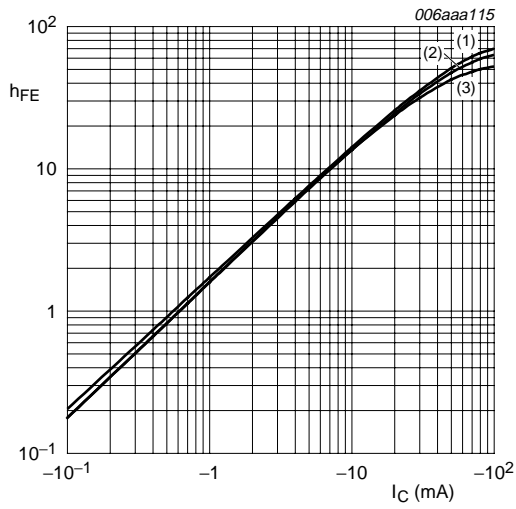
[2] Reflow soldering is the only recommended soldering method.

[3] Refer to SOT883 standard mounting conditions; FR4 printed-circuit board with 60  $\mu$ m copper strip line.

## 7. Characteristics

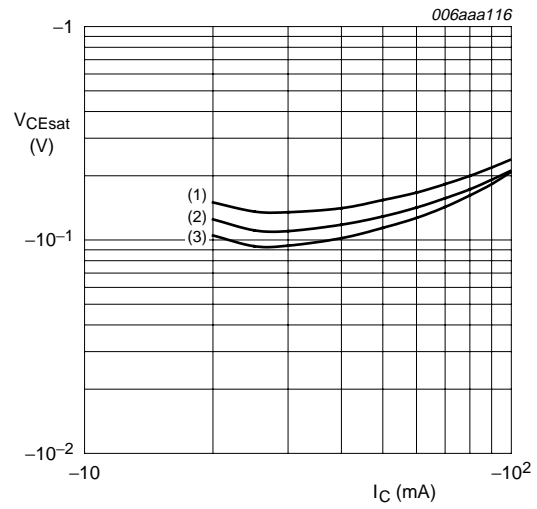
**Table 8. Characteristics**
*T<sub>amb</sub> = 25 °C unless otherwise specified*

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
I <sub>CBO</sub>	collector-base cut-off current	V <sub>CB</sub> = -50 V; I <sub>E</sub> = 0 A	-	-	-100	nA
I <sub>CEO</sub>	collector-emitter cut-off current	V <sub>CE</sub> = -30 V; I <sub>B</sub> = 0 A	-	-	-1	$\mu$ A
		V <sub>CE</sub> = -30 V; I <sub>B</sub> = 0 A; T <sub>j</sub> = 150 °C	-	-	-50	$\mu$ A
I <sub>EBO</sub>	emitter-base cut-off current	V <sub>EB</sub> = -5 V; I <sub>C</sub> = 0 A	-	-	-4	mA
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = -5 V; I <sub>C</sub> = -40 mA	30	-	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	I <sub>C</sub> = -30 mA; I <sub>B</sub> = -1.5 mA	-	-	-150	mV
V <sub>I(off)</sub>	off-state input voltage	V <sub>CE</sub> = -5 V; I <sub>C</sub> = -100 $\mu$ A	-	-1.3	-0.5	V
V <sub>I(on)</sub>	on-state input voltage	V <sub>CE</sub> = -300 mV; I <sub>C</sub> = -20 mA	-2	-1.7	-	V
R1	bias resistor 1 (input)		0.7	1	1.3	k $\Omega$
R2/R1	bias resistor ratio		0.8	1	1.2	
C <sub>c</sub>	collector capacitance	V <sub>CB</sub> = -10 V; I <sub>E</sub> = i <sub>e</sub> = 0 A; f = 1 MHz	-	-	2	pF



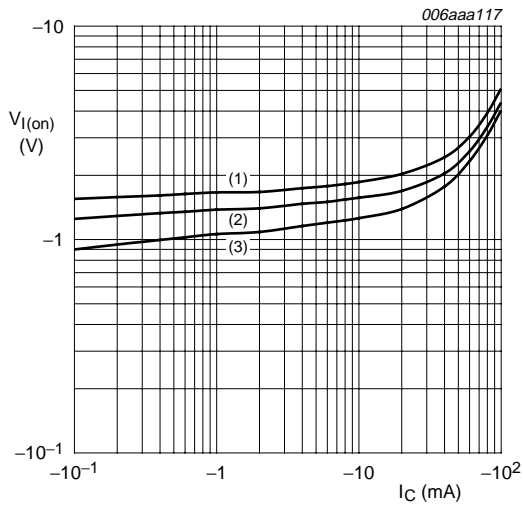
$V_{CE} = -5 \text{ V}$   
 (1)  $T_{amb} = 100 \text{ }^\circ\text{C}$   
 (2)  $T_{amb} = 25 \text{ }^\circ\text{C}$   
 (3)  $T_{amb} = -40 \text{ }^\circ\text{C}$

**Fig 1. DC current gain as a function of collector current; typical values**



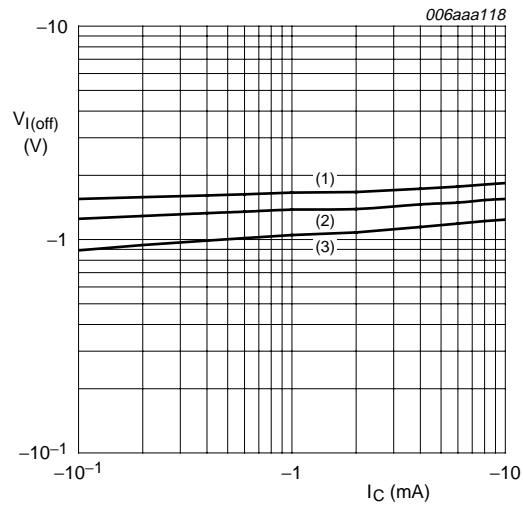
$I_C/I_B = 20$   
 (1)  $T_{amb} = 100 \text{ }^\circ\text{C}$   
 (2)  $T_{amb} = 25 \text{ }^\circ\text{C}$   
 (3)  $T_{amb} = -40 \text{ }^\circ\text{C}$

**Fig 2. Collector-emitter saturation voltage as a function of collector current; typical values**



$V_{CE} = -0.3 \text{ V}$   
 (1)  $T_{amb} = -40 \text{ }^\circ\text{C}$   
 (2)  $T_{amb} = 25 \text{ }^\circ\text{C}$   
 (3)  $T_{amb} = 100 \text{ }^\circ\text{C}$

**Fig 3. On-state input voltage as a function of collector current; typical values**



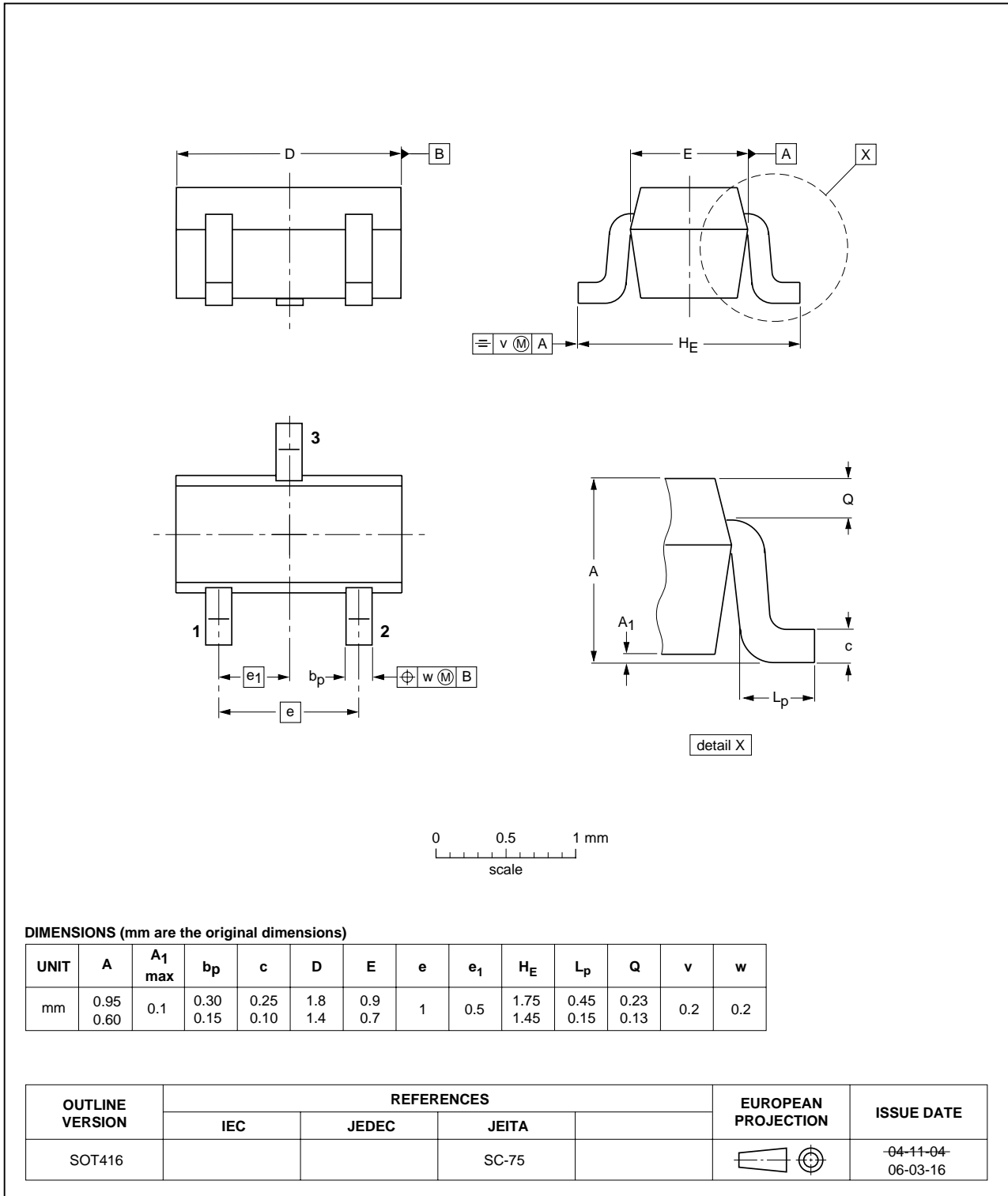
$V_{CE} = -5 \text{ V}$   
 (1)  $T_{amb} = -40 \text{ }^\circ\text{C}$   
 (2)  $T_{amb} = 25 \text{ }^\circ\text{C}$   
 (3)  $T_{amb} = 100 \text{ }^\circ\text{C}$

**Fig 4. Off-state input voltage as a function of collector current; typical values**

**8. Package outline**

Plastic surface-mounted package; 3 leads

SOT416



**Fig 5. Package outline SOT416 (SC-75)**



Plastic surface-mounted package; 3 leads

SOT346

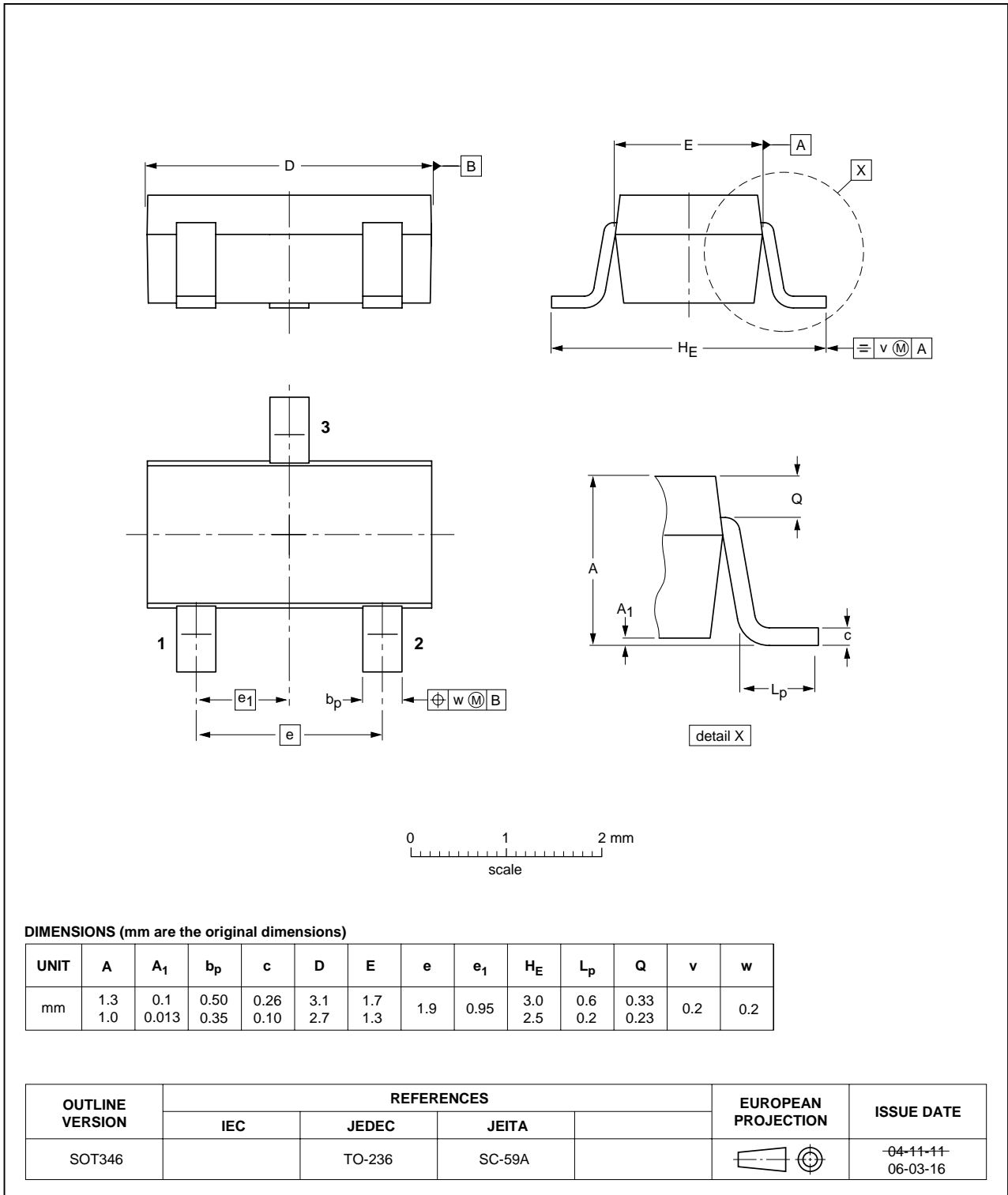


Fig 6. Package outline SOT346 (SC-59A/TO-236)

Leadless ultra small plastic package; 3 solder lands; body 1.0 x 0.6 x 0.5 mm

SOT883



Fig 7. Package outline SOT883 (SC-101)

Plastic single-ended leaded (through hole) package; 3 leads

SOT54



Fig 8. Package outline SOT54 (SC-43A/TO-92)

Plastic single-ended leaded (through hole) package; 3 leads (wide pitch)

SOT54A



Fig 9. Package outline SOT54A

Plastic single-ended leaded (through hole) package; 3 leads (on-circle)

SOT54 variant



Fig 10. Package outline SOT54 variant

Plastic surface-mounted package; 3 leads

SOT23



Fig 11. Package outline SOT23 (TO-236AB)

Plastic surface-mounted package; 3 leads

SOT323



Fig 12. Package outline SOT323 (SC-70)

## 9. Packing information

**Table 9. Packing methods**

The indicated -xxx are the last three digits of the 12NC ordering code. [1]

Type number	Package	Description	Packing quantity		
			3000	5000	10000
PDTA113EE	SOT416	4 mm pitch, 8 mm tape and reel	-115	-	-135
PDTA113EK	SOT346	4 mm pitch, 8 mm tape and reel	-115	-	-135
PDTA113EM	SOT883	2 mm pitch, 8 mm tape and reel	-	-	-315
PDTA113ES	SOT54	bulk, straight leads	-	-412	-
	SOT54A	tape and reel, wide pitch	-	-	-116
	SOT54A	tape ammopack, wide patch	-	-	-126
	SOT54 variant	bulk, delta pinning	-	-112	-
PDTA113ET	SOT23	4 mm pitch, 8 mm tape and reel	-215	-	-235
PDTA113EU	SOT323	4 mm pitch, 8 mm tape and reel	-115	-	-135

[1] For further information and the availability of packing methods, see [Section 12](#).



## 10. Revision history

**Table 10. Revision history**

Document ID	Release date	Data sheet status	Change notice	Supersedes
PDTA113E_SER_5	20090902	Product data sheet	-	PDTA113E_SER_4
Modifications:		<ul style="list-style-type: none"> <li>This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content.</li> <li><a href="#">Figure 5 "Package outline SOT416 (SC-75)"</a> updated</li> <li><a href="#">Figure 6 "Package outline SOT346 (SC-59A/TO-236)"</a> updated</li> <li><a href="#">Figure 11 "Package outline SOT23 (TO-236AB)"</a> updated</li> <li><a href="#">Figure 12 "Package outline SOT323 (SC-70)"</a> updated</li> </ul>		
PDTA113E_SER_4	20050405	Product data sheet	-	PDTA113ET_3
PDTA113ET_3	20040720	Objective data sheet	-	PDTA113ET_2
PDTA113ET_2	20040415	Objective data sheet	-	PDTA113ET_1
PDTA113ET_1	20040316	Objective data sheet	-	-

## 11. Legal information

### 11.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

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